MAMXSS0010

MMIC Medium Level Mixer
1700 - 2000 MHz

Rev. V3

Features

- Low Conversion Loss
- Input Power @ 1 dB Compression: +21 dBm
- Typical Two-Tone IM Ratio: ≥ 50 dBc
- LO Drive Level: +11 to +23 dBm
- DC - 200 MHz IF Bandwidth
- Lead-Free SOIC-8 Package
- 100% Matte Tin Plating over Copper
- Halogen-Free "Green" Mold Compound
- 260°C Reflow Compatible
- RoHS* Compliant Version of MD54-0003

Description

M/A-COM's MAMXSS0010 is a passive mixer that achieves the performance of a double balanced diode mixer in a lead-free surface mount plastic SOIC-8 package. The MAMXSS0010 is ideally suited for use where high level RF signals and very wide dynamic range are required.

Typical applications include frequency up/down conversion, modulation, demodulation in systems such as base station receivers and transmitters for DCS1800, PCS and PHS applications.

The MAMXSS0010 uses FETs as mixing elements to achieve very wide dynamic range in a low cost plastic package. The mixer operates with LO drive levels of +11 dBm to +23 dBm. No DC bias is required.

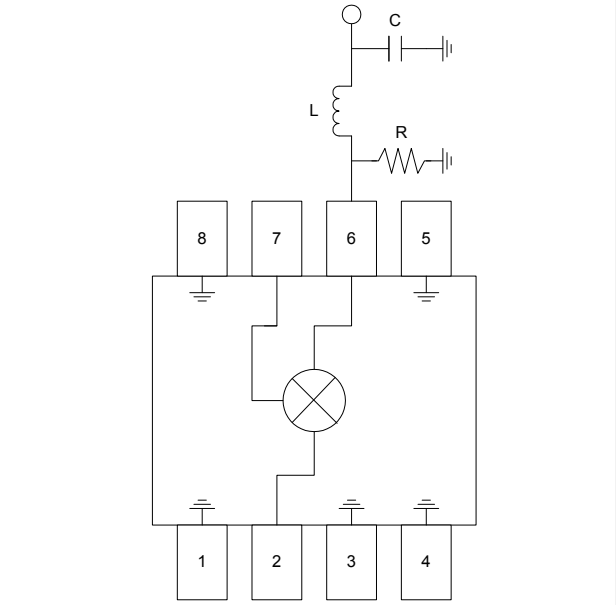
M/A-COM's MAMXSS0010 is fabricated using a mature 1-micron GaAs process. The process features full IC passivation for increased performance and reliability.

Ordering Information

Part Number	Package
MAMXSS0010	Bulk Packaging
MAMXSS0010TR	1000 piece reel
MAMXSS0010SMB	Designer's Kit

1. Reference Application Note M513 for reel size information.

Functional Diagram



External matching network on LO Port: R = 330 ohms, L = 3 nH, C = 3.3 pF

Pin Configuration

Pin No.	Function	Pin No.	Function
1	Ground	5	Ground
2	RF Port	6	LO Port
3	Ground	7	IF Port
4	Ground	8	Ground

* Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

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Electrical Specifications:
Test Conditions: RF = 1850 MHz (-10 dBm), LO = 1710 MHz (13 dBm), IF = 140 MHz, T_A = +25°C

Parameter	Test Conditions	Units	Min	Typ	Max
Conversion Loss	—	dB	—	8.5	9.5
Isolation	LO to RF LO to IF RF to IF	dB dB dB	— — —	27 12 10	— — —
VSWR	LO Port RF Port IF Port	Ratio Ratio Ratio	— — —	2.5:1 2.0:1 2.0:1	— — —
Input 1 dB Compression	RF Freq. = 1800 MHz, LO = +13 dBm	dBm	—	+21	—
Two-Tone IM Ratio[2]	Two tones at –10 dBm each, Tone spacing 100 kHz, IF = 140 MHz	dBc	50	65	—

2. IMR vs RF drive level can be calculated by the formula: IMR = 50 - (1.5 x P_{IN})

Absolute Maximum Ratings [3,4]

Parameter	Absolute Maximum
RF Input Power[5]	+22 dBm
LO Drive Power[5]	+23 dBm
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C

3. Exceeding any one or combination of these limits may cause permanent damage to this device.
4. M/A-COM does not recommend sustained operation near these survivability limits.
5. Total combined power for RF and LO ports should not exceed +23 dBm.

Handling Procedures
Please observe the following precautions to avoid damage:

Static Sensitivity
Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

Spurious Table

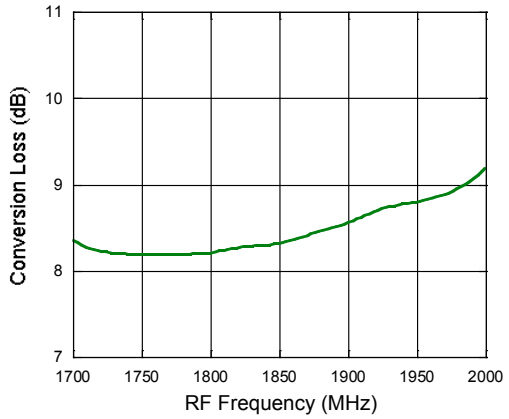
Harmonic of LO	0x	1x	2x	3x	4x
4x	17 6.9	48.2 47.2	62.3 61.1	71.7 61.7	73.4 63.4
3x	10.3 0.3	28.9 28.9	63.0 61.3	71.3 63.5	70.6 61.6
2x	-8.8 -18.8	-25.7 25.9	52.1 61.3	71.5 61.5	72.1 62.1
1x	-13.1 -23.1	0 0	67.5 61.1	71.3 61.9	72.6 62.6
0x	X X	2.1 2.1	56.8 61.7	72.3 62.3	69.3 59.8
	0x	**1x**	**2x**	**3x**	**4x**
	Harmonic of RF				

The spurious table shows the spurious signals resulting from the mixing of the RF and LO input signals, assuming down conversion. Mixing products are indicated by the number of dB below the conversion loss. The lower frequency mixing term is shown for two different RF input levels. The top number is for an RF input power of -5 dBm, the lower number is for -15 dBm.

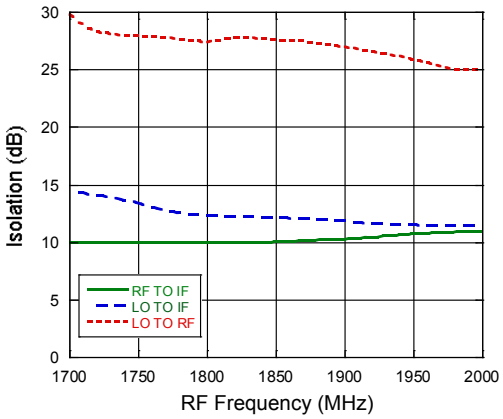
$|mF_{RF} - nF_{LO}|$, RF = -5 dBm
$|mF_{RF} - nF_{LO}|$, RF = -15 dBm
RF Frequency = 1850 MHz
LO Frequency = 1710 MHz

Typical Performance Curves

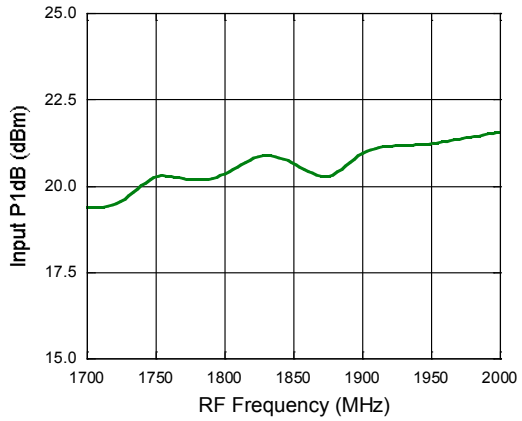
Conversion Loss



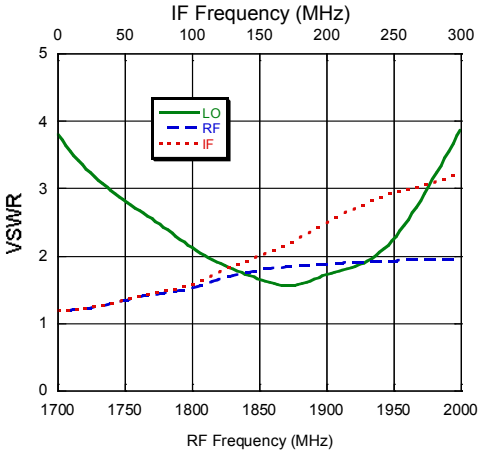
Isolation



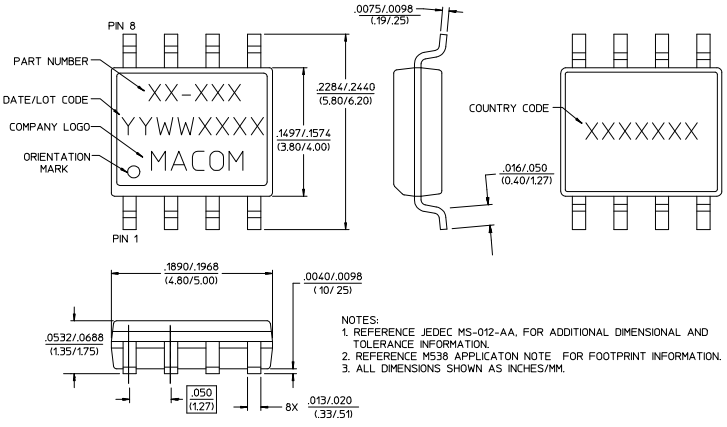
Input P1dB



RF, LO and IF VSWR



Lead-Free SOIC-8†



† Reference Application Note M538 for lead-free solder reflow recommendations.